SCLS391D - APRIL 1998 - REVISED MAY 2000

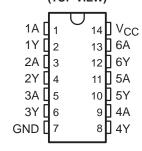
- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- 2-V to 5.5-V V_{CC} Operation
- Support Mixed-Mode Voltage Operation on All Ports
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (D, NS), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Packages, Chip Carriers (FK), and DIPs (J)

description

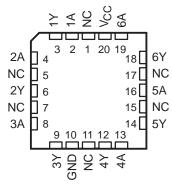
The 'LV05A devices contain six independent inverters designed for 2-V to 5.5-V $\rm V_{CC}$ operation.

These devices perform the Boolean function $\bigvee -\overline{\Delta}$

SN54LV05A . . . J OR W PACKAGE SN74LV05A . . . D, DB, DGV, NS, OR PW PACKAGE (TOP VIEW)



SN54LV05A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

The open-drain outputs require pullup resistors to perform correctly and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions.

The SN54LV05A is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74LV05A is characterized for operation from -40° C to 85° C.

FUNCTION TABLE (each inverter)

INPUT A	OUTPUT Y
Н	L
L	Н

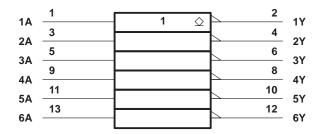


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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, NS, PW, and W packages.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range, V _I (see Note 1)		–0.5 V to 7 V
Voltage range applied to any output in the high		
or power-off state, V _O (see Note 1)		0.5 V to 7 V
Output voltage range, VO (see Notes 1 and 2)		$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$)		—20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CO}	c)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$		±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ _{JA} (see Note 3)): D package	86°C/W
	DB package	96°C/W
	DGV package	127°C/W
	NS package	76°C/W
	PW package	113°C/W
Storage temperature range, T _{stq}		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. This value is limited to 5.5 V maximum.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.



recommended operating conditions (see Note 4)

			SN54L	-V05A	SN74L	_V05A	UNIT	
			MIN	MAX	MIN	MAX	UNII	
Vсс	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
\/	High level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	V _{CC} ×0.7		V _{CC} ×0.7		V	
VIH	High-level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} ×0.7		V _{CC} ×0.7		V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	V _{CC} ×0.7		V _{CC} ×0.7			
		V _{CC} = 2 V		0.5		0.5		
\ \/	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		V _{CC} × 0.3		$V_{CC} \times 0.3$	V	
VIL		V _{CC} = 3 V to 3.6 V		VCC×0.3		V _{CC} ×0.3	ľ	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		V _{CC} ×0.3		$V_{CC} \times 0.3$		
٧ _I	Input voltage		0	5.5	0	5.5	V	
٧o	Output voltage		0,0	Vcc	0	Vcc	V	
		V _{CC} = 2 V	Q	50		50	μΑ	
	Low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	Q.	2		2		
IOL	Low-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		6		6	mA	
		V _{CC} = 4.5 V to 5.5 V		12		12		
		V _{CC} = 2.3 V to 2.7 V	0	200	0	200		
Δt/Δν	Input transition rise or fall rate	V _{CC} = 3 V to 3.6 V	0	100	0	100	ns/V	
		V _{CC} = 4.5 V to 5.5 V	0	20	0	20		
T _A	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	.,	SN54LV05A	SN74LV05A	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN TYP MAX	MIN TYP MAX	UNIT
	I _{OL} = 50 μA	2 V to 5.5 V	0.1	0.1	
Voi	I _{OL} = 2 mA	2.3 V	0.4	0.4	V
VOL	I _{OL} = 6 mA	3 V	0.44	0.44	v
	I _{OL} = 12 mA	4.5 V	0.55	0.55	
lį	$V_I = V_{CC}$ or GND	0 V to 5.5 V	5 ±1	±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	20	20	μΑ
loff	V_I or $V_O = 0$ to 5.5 V	0 V	5	5	μΑ
Ci	$V_I = V_{CC}$ or GND	3.3 V	2.5	2.5	pF

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	չ = 25°C	;	SN54LV0)5A	SN74L	V05A	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN N	MAX	MIN	MAX	UNIT	
t _{PLZ}	۸		C _I = 15 pF		3.6*	10.4*	1*	13*	1	13	ns	
t _{PZL}	A	A	ı	OL = 15 pr		5.8*	12.2*	1*\	15*	1	15	115
^t PLZ	Δ.	~	C: - 50 pF		6.1	15.2	POLY	18	1	18	20	
^t PZL	A	ſ	С _L = 50 pF		8.1	16.6	81	19.5	1	19.5	ns	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	չ = 25°C	;	SN54LV05	Α	SN74L	V05A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN MA	٩X	MIN	MAX	UNIT
tPLZ	А		C _I = 15 pF		2.9*	7.1*	1* 8	.5*	1	8.5	ns
t _{PZL}	1 ^	A T CL	C[= 13 μ		4*	7.1*	1*\\\	.5*	1	8.5	115
^t PLZ	Δ.	V	C: - 50 pF		4.7	10.6	SEOFALL S	12	1	12	20
^t PZL	A	ſ	$C_L = 50 \text{ pF}$		5.8	10.6	81	12	1	12	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Վ = 25° C	;	SN54LV	05A	SN74L	V05A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLZ}	^		C _I = 15 pF		2.2*	5.5*	1*	6.5*	1	6.5	ns
t _{PZL}	A	A 1 CL = 13 pr	GE = 13 bi		2.9*	5.5*	1*3	6.5*	1	6.5	115
^t PLZ	A Y CL	~	C _I = 50 pF		3.4	7.5	PO VIII	8.5	1	8.5	ns
^t PZL		OL = 50 pr		4.2	7.5	V 1	8.5	1	8.5	115	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

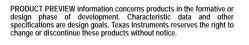
noise characteristics, $V_{CC} = 3.3 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 5)

	PARAMETER		SN74LV05A			
	PARAMETER	MIN TYP M. 0.55	MAX	UNIT		
VOL(P)	Quiet output, maximum dynamic VOL		0.55	0.8	V	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.04	-0.8	V	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		3.12		V	
VIH(D)	High-level dynamic input voltage	2.31			V	
V _{IL(D)}	Low-level dynamic input voltage			0.97	V	

NOTE 5: Characteristics are for surface-mount packages only.

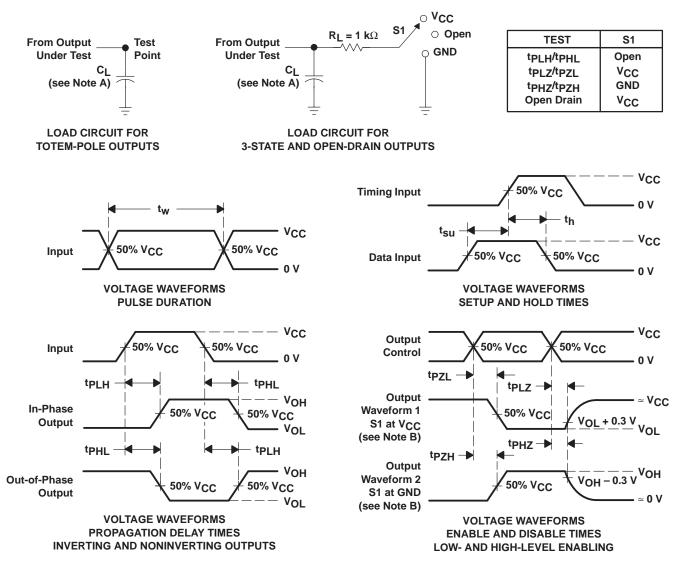
operating characteristics, T_A = 25°C

PARAMETER		TEST CO	VCC	TYP	UNIT	
C _{pd}	Power dissipation capacitance	C _L = 50 pF,	f _ 10 MH=	3.3 V	2.5	nE.
			f = 10 MHz	5 V	3	pF





PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_Q = 50 \Omega$, $t_f \leq 3$ ns, $t_f \leq 3$ ns.
 - D. The outputs are measured one at a time with one input transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpHL and tpLH are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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